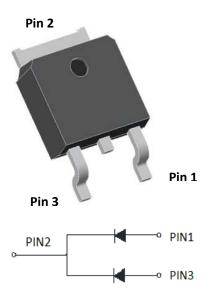


### MBR6100CD





# **Schottky Diodes**

#### **Features**

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

• Package: TO-252

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

-maximum ratings (14 = 1 = 1 maximum specimen)				
PARAMETER	SYMBOL	UNIT	MBR6100CD	
Device marking code			MBR6100CD	
Repetitive Peak Reverse Voltage	VRRM	V	100	
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25℃	lo	А	6	
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, $T_a$ =25 $^{\circ}$ C	IFSM	А	120	
Current Squared Time @1ms≤t<8.3ms Tj=25℃,	l <sup>2</sup> t	A <sup>2</sup> s	60	
Storage Temperature	T <sub>stg</sub>	$^{\circ}$	-55 ~ +175	
Junction Temperature	Tj	$^{\circ}$	-55 ~ <b>+</b> 175	

### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR6100CD
Maximum instantaneous forward voltage drop per diode	VFM	٧	IFM=3.0A	0.76
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T <sub>a</sub> =25°C	0.1
	IRRM2		VRM=VRRM T <sub>a</sub> =125°C	20

## **MBR6100CD**

### **Thermal Characteristics** $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARA	METER	SYMBOL	UNIT	MBR6100CD
Thermal Resistance	Between junction and case	R <sub>θJ-C</sub>	°CMV	5.0

**■Ordering Information** (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR6100CD	Approximate 0.32	2500	2500	25000	Reel

### **■Characteristics** (Typical)

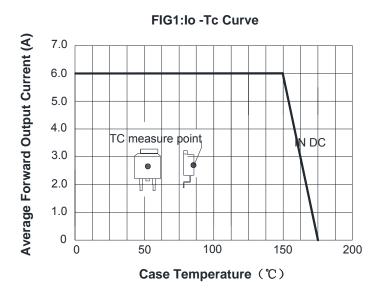


FIG2:Surge Forward Current Capability

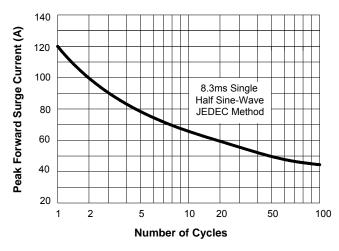


FIG3: Forward Voltage

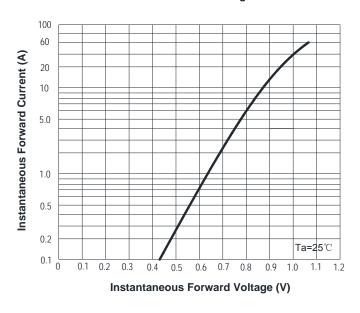
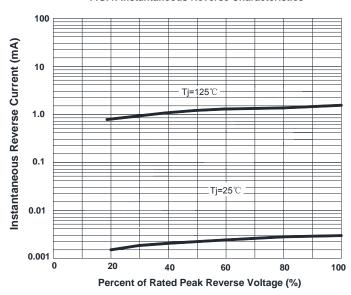


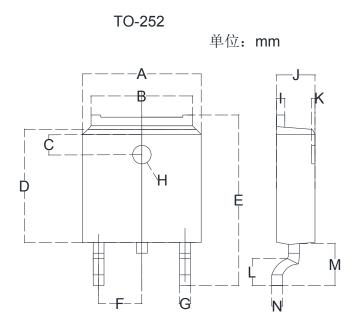
FIG.4: Instantaneous Reverse Characteristics







### **■**Outline Dimensions



TO-252				
Dim	Min	Max		
Α	6.500	6.700		
В	5.100	5.460		
С	1.400	1.800		
D	6.000	6.200		
Е	10.000	10.400		
F	2.166	2.366		
G	0.660	0.860		
Н	Ф1.050	Ф1.350		
I	0.460	0.580		
J	2.200	2.400		
K	0	0.300		
L	0.890	2.290		
М	2.730	3.080		
N	0.430	0.580		



### MBR6100CD

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